**Vishay Semiconductors** 

High Performance Schottky Rectifier, 1 A



Cathode Anode -0

DO-214AC (SMA)

PRODUCT SUMMARY				
Package	DO-214AC (SMA)			
I <sub>F(AV)</sub>	1 A			
V <sub>R</sub>	40 V			
V <sub>F</sub> at I <sub>F</sub>	0.54 V			
I <sub>RM</sub>	26 mA at 125 °C			
T <sub>J</sub> max.	150 °C			
Diode variation	Single die			
E <sub>AS</sub>	3.0 mJ			

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### **FEATURES**

- · Small foot print, surface mountable
- Low forward voltage drop High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### DESCRIPTION

The VS-10MQ040NPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS VALUES U				
I <sub>F(AV)</sub>	Rectangular waveform	1	А		
V <sub>RRM</sub>		40	V		
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	120	А		
V <sub>F</sub>	1.5 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.56	V		
TJ	Range	-55 to +150	°C		

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-10MQ040NPbF	UNITS
Maximum DC reverse voltage	V <sub>R</sub>	40	V
Maximum working peak reverse voltage	V <sub>RWM</sub>	40	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current		50 % duty cycle at $T_L$ = 123 °C, On PC board 9 mm <sup>2</sup> island (0.013	rectangular waveform 3 mm thick copper pad area)	1.5	
See fig. 4		50 % duty cycle at $T_L$ = 132 °C, rectangular waveform On PC board 9 mm <sup>2</sup> island (0.013 mm thick copper pad area)		1	A
Maximum peak one cycle		5 µs sine or 3 µs rect. pulse	Following any rated load	120	_
non-repetitive surge current See fig. 6	I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	condition and with rated V <sub>RRM</sub> applied	30	A
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1 A, L = 6 mH		3.0	mJ
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		1.0	А

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
		1 A	T <sub>.1</sub> = 25 °C	0.54	V
Maximum forward voltage drop	V (1)	1.5 A	1j=25 0	0.62	
See fig. 1	V <sub>FM</sub> <sup>(1)</sup>	1 A	T <sub>J</sub> = 125 °C	0.49	
		1.5 A		0.56	
Maximum reverse leakage current	I <sub>BM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	V <sub>R</sub> = Rated V <sub>R</sub>	0.5	mA
See fig. 2	IRM \''	T <sub>J</sub> = 125 °C		26	
Threshold voltage	V <sub>F(TO)</sub>	$T_{\rm J} = T_{\rm J} \text{ maximum} \qquad \qquad \frac{0.36}{104}$		0.36	V
Forward slope resistance	r <sub>t</sub>			mΩ	
Typical junction capacitance	CT	$V_R = 10 V_{DC}$ , $T_J = 25 \text{ °C}$ , test signal = 1 MHz		38	pF
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body		2.0	nH
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub> 10 000 V/µ		V/µs	

#### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	$T_{J}$ <sup>(1)</sup> , $T_{Stg}$		-55 to +150	°C
Maximum thermal resistance, junction to ambient	R <sub>thJA</sub>	DC operation	80	°C/W
Approvimete weight			0.07	g
Approximate weight			0.002	oz.
Marking device		Case style SMA (similar D-64)	1	F

#### Note

 $^{(1)} \quad \frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$ 



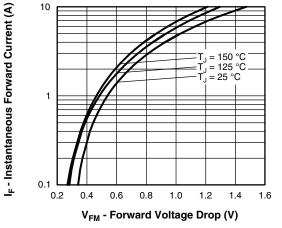


Fig. 1 - Maximum Forward Voltage Drop Characteristics

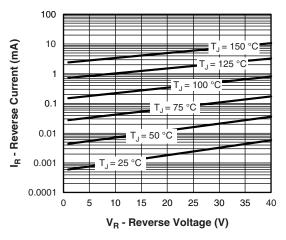


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

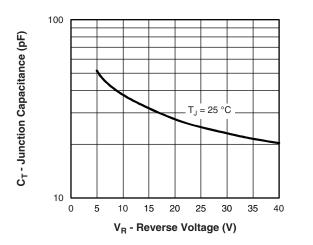


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see fig. 6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$ 

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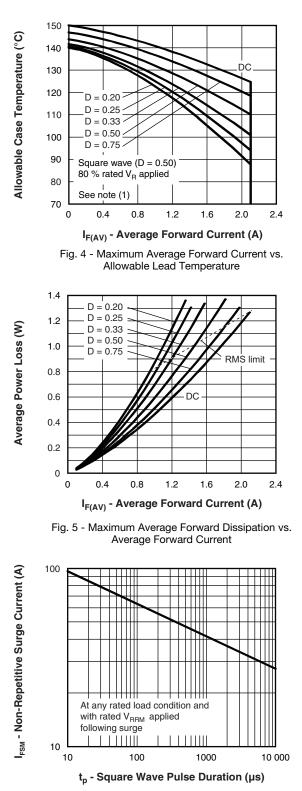


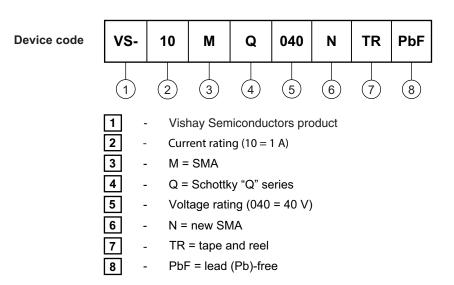
Fig. 6 - Maximum Peak Surge Forward Current vs. Pulse Duration

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#### **ORDERING INFORMATION TABLE**



ORDERING INFORMATION (Example)					
PREFERRED P/N	PREFERRED PACKAGE CODE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-10MQ040NTRPbF	5AT	7500	13" diameter plastic tape and reel		

LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?95400				
Part marking information	www.vishay.com/doc?95403			
Packaging information	www.vishay.com/doc?95404			
SPICE model	www.vishay.com/doc?95277			
SPICE model	www.vishay.com/doc?96007			



# **Outline Dimensions**

### **Vishay Semiconductors**

SMA

#### **DIMENSIONS** in inches (millimeters)

DO-214AC (SMA)





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